NSN 5961-00-059-5219

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Inclosure Material:	
Metal	
Overall Length:	
0.210 inches	
Terminal Length:	
0.500 inches	
Overall Diameter:	
0.230 inches	
Internal Configuration:	
Junction contact	
Electrode Internally-electrically Connected To Case:	
Collector	
Mounting Method:	
Terminal	
Terminal Circle Diameter:	
0.100 inches	
Features Provided:	
Hermetically sealed case	
Semiconductor Material:	
Silicon	
Voltage Rating In Volts Per Characteristic:	
56.0 breakdown voltage, collector-to-base, emitter open and 28.0 breakdown vo	oltage, collector-to-emitter, base open and 4.0 breakdown
voltage, emitter-to-base, collector open	
Power Rating Per Characteristic:	
300.0 milliwatts small-signal input power, common-collector	
Maximum Operating Tempurature Per Measurement Point:	
200.0 degrees celsius junction	
Special Features:	
Junction pattern arrangement: npn	
Terminal Type And Quantity:	
3 uninsulated wire lead	
Specification Data:	
80131-release2781 professional/industrial association specification	
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
No	
Fiig:	
A110a0	